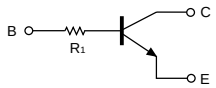
Digital transistors (built-in resistor)

DTC143TM / DTC143TE / DTC143TUA / DTC143TKA / DTC143TSA

●Features

1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3) Only the on/off conditions need to be set for operation, making device design easy.

●Equivalent circuit



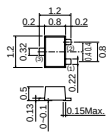
B : Base
C : Collector
E : Emitter

●Structure

PNP digital transistor
(Built-in resistor type)

●External dimensions (Units : mm)

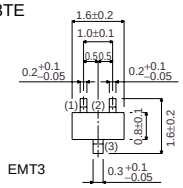
DTC143TM



ROHM : VMT3
Abbreviated symbol : 03

(1) Base
(2) Emitter
(3) Collector

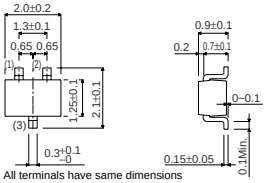
DTC143TE



ROHM : EMT3
Abbreviated symbol : 03

(1) Emitter
(2) Base
(3) Collector

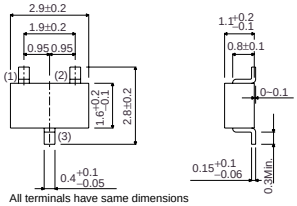
DTC143TUA



ROHM : UMT3
EIAJ : SC-70
All terminals have same dimensions
Abbreviated symbol : 03

(1) Emitter
(2) Base
(3) Collector

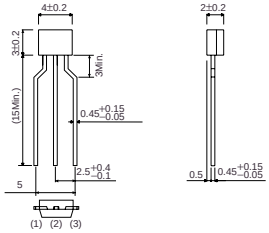
DTC143TKA



ROHM : SMT3
EIAJ : SC-59
All terminals have same dimensions
Abbreviated symbol : 03

(1) Emitter
(2) Base
(3) Collector

DTC143TSA



ROHM : SPT
EIAJ : SC-72

(1) Emitter
(2) Collector
(3) Base

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits(DTC143T□)					Unit
		M	E	UA	KA	SA	
Collector-base voltage	V_{CBO}	50					V
Collector-emitter voltage	V_{CEO}	50					V
Emitter-base voltage	V_{EBO}	5					V
Collector current	I_C	100					mA
Collector power dissipation	P_C	150		200		300	mW
Junction temperature	Tj	150					°C
Storage temperature	Tstg	−55~+150					°C

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	50	–	–	V	I_C=50μA
Collector-emitter breakdown voltage	BV_{CEO}	50	–	–	V	I_C=1mA
Emitter-base breakdown voltage	BV_{EBO}	5	–	–	V	I_E=50μA
Collector cutoff current	I_{CBO}	–	–	0.5	μA	V_{CB}=50V
Emitter cutoff current	I_{EBO}	–	–	0.5	μA	V_{EB}=4V
Collector-emitter saturation voltage	$V_{CE(sat)}$	–	–	0.3	V	I_C/I_B=5mA/0.25mA
DC current transfer ratio	h_{FE}	100	250	600	–	I_C=1mA, V_{CE}=5V
Input resistance	R_1	3.29	4.7	6.11	kΩ	–
Transition frequency	f_T	–	250	–	MHz	V_{CE}=10V, I_E=−5mA, f=100MHz ＊

＊ Transition frequency of the device

●Packaging specifications

Type	Package	VMT3	EMT3	UMT3	SMT3	SPT
	Packaging type	Taping	Taping	Taping	Taping	Taping
	Code	T2L	TL	T106	T146	TP
	Basic ordering unit (pieces)	8000	3000	3000	3000	5000
DTC143TM		○	–	–	–	–
DTC143TE		–	○	–	–	–
DTC143TUA		–	–	○	–	–
DTC143TKA		–	–	–	○	–
DTC143TSA		–	–	–	–	○

●**Electrical characteristic curves**

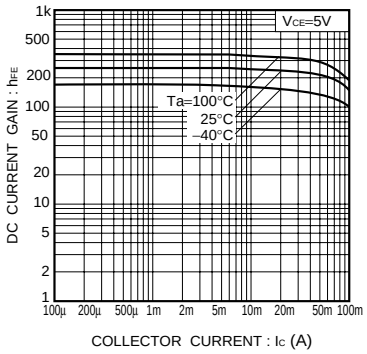


Fig.1 DC current gain vs. collector current

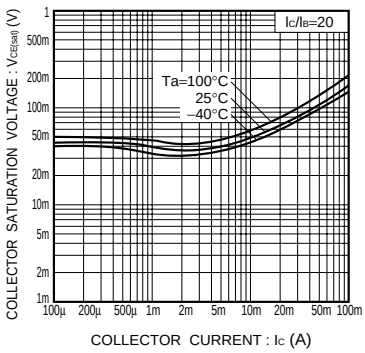


Fig.2 Collector-emitter saturation voltage vs. collector current

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